

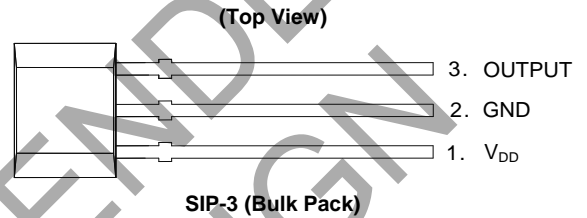
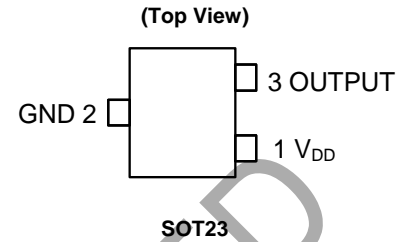
HIGH VOLTAGE HIGH SENSITIVITY  
AUTOMOTIVE HALL EFFECT OMNIPOLAR SWITCH

## Description

The AH3563Q is an AEC-Q100 qualified high-voltage, high-sensitivity Hall effect omnipolar switch IC designed for position and proximity sensing in automotive applications, such as in seat and seatbelt buckle, steering lock/immobilization, gear stick, transmission actuator and gear position, HVAC compression, wiper, door/trunk closure, and so on. To support a wide range of demanding applications, the design is optimized to operate over the supply range of 3.0V to 28V. With chopper-stabilized architecture and an internal bandgap regulator to provide temperature compensated supply for internal circuits, the AH3563Q provides a reliable solution over the whole operating range. For robustness and protection, the device has a reverse blocking diode with a zener clamp on the supply. The output has an overcurrent limit and a zener clamp.

The single open-drain output can be switched on with south or north pole of sufficient strength. When the magnetic flux density (B) perpendicular to the package is larger than the operate point (B<sub>OP</sub>), the output is switched on (pulled low) and is held on until the magnetic flux density B is lower than the release point (B<sub>RP</sub>).

## Pin Assignments



## Features

- Omnipolar Operation
- High Sensitivity: B<sub>OP</sub> and B<sub>RP</sub> of ±30G and ±20G Typical
- Single Open-Drain Output with Overcurrent Limit
- 3.0V to 28V Operating Voltage Range
- Chopper Stabilized Design Provides
  - Superior Temperature Stability
  - Minimal Switch Point Drift
  - Enhanced Immunity to Stress
- Good RF Noise Immunity
- Reverse Blocking Diode
- Zener Clamp on Supply and Output Pins
- -40°C to +150°C Operating Temperature
- ESD: HBM > 8kV, CDM > 2kV
- Industry Standard SOT23 and SIP-3 (Ammo Pack), SIP-3 (Bulk Pack) Packages
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **The AH3563Q is suitable for automotive applications requiring specific change control; this part is AEC-Q100 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.**

<https://www.diodes.com/quality/product-definitions/>

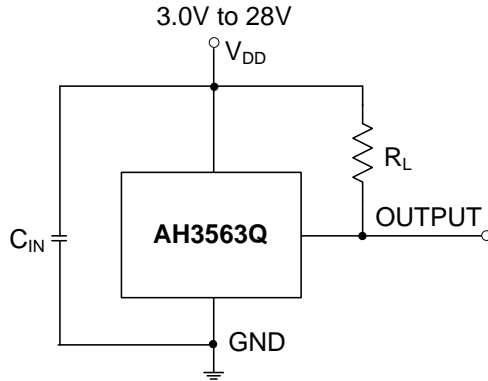
## Applications

- Position and Proximity Sensing in Automotive Applications
- Open and Close Detect
- Position Detect
- Level Detect
- Flow Meters
- Contactless Switches
- Seatbelt Buckle
- Seat Position

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

**Typical Applications Circuit**



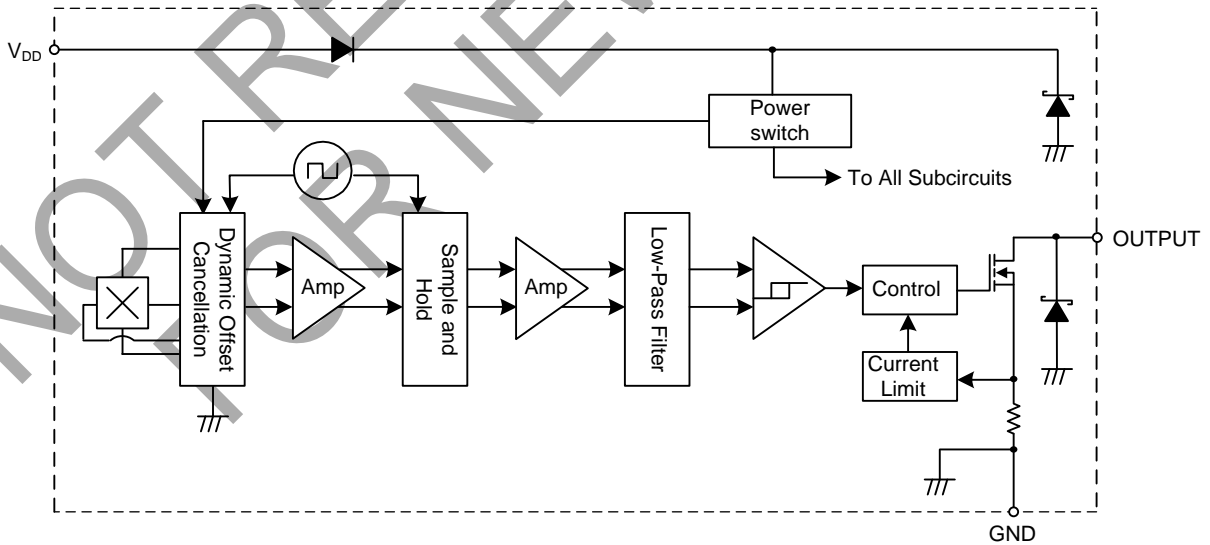
Note: 4.  $C_{IN}$  is for power stabilization and to strengthen the noise immunity; the recommended capacitance is 10nF ~ 100nF.

**Pin Descriptions**

Packages: SOT23 and SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)

Pin Number	Pin Name	Function
1	V <sub>DD</sub>	Power Supply Input
2	GND	Ground
3	OUTPUT	Output Pin

**Functional Block Diagram**



**Absolute Maximum Ratings** (Notes 5 and 6) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Characteristic	Value	Unit	
V <sub>DD</sub>	Supply Voltage (Note 6)	32	V	
V <sub>DDR</sub>	Reverse Supply Voltage (Note 6)	-32	V	
V <sub>OUT_MAX</sub>	Output Off Voltage (Note 6)	32	V	
I <sub>OUT</sub>	Continuous Output Current	60	mA	
I <sub>OUT_R</sub>	Reverse Output Current	-50	mA	
B	Magnetic Flux Density	Unlimited		
P <sub>D</sub>	Package Power Dissipation	SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)	550	mW
		SOT23	230	
T <sub>S</sub>	Storage Temperature Range	-65 to +165	°C	
T <sub>J</sub>	Maximum Junction Temperature	+150	°C	
ESD HBM	Electrostatic Discharge Withstand — Human Body Model (HBM)	8	kV	
ESD MM	Electrostatic Discharge Withstand — Machine Model (MM)	800	V	
ESD CDM	Electrostatic Discharge Withstand — Charged Device Model (CDM)	2	kV	

- Notes:
- Stresses greater than the 'Absolute Maximum Ratings' specified above can cause permanent damage to the device. These are stress ratings only; functional operation of the device at these or any other conditions exceeding those indicated in this specification is not implied. Device reliability may be affected by exposure to absolute maximum rating conditions for extended periods of time.
  - The absolute maximum V<sub>DD</sub> of 32V is a transient stress rating and is not meant as a functional operating condition. It is not recommended to operate the device at the absolute maximum rated conditions for any period of time.

**Recommended Operating Conditions** (@T<sub>A</sub> = -40°C to +150°C, unless otherwise specified.)

Symbol	Parameter	Condition	Rating	Unit
V <sub>DD</sub>	Supply Voltage	Operating	3.0 to 28	V
T <sub>A</sub>	Operating Temperature Range	Operating	-40 to +150	°C

**Electrical Characteristics** (Notes 7 and 8) (@T<sub>A</sub> = -40°C to +150°C, V<sub>DD</sub> = 3V to 28V, unless otherwise specified.)

Symbol	Parameter	Condition	Min	Typ	Max	Unit
V <sub>OUT_ON</sub>	Output On Voltage	I <sub>OUT</sub> = 20mA, B > B <sub>OP</sub>	—	0.2	0.4	V
I <sub>LKG</sub>	Output Leakage Current (When Output is Off)	V <sub>OUT</sub> = 28V, B < B <sub>RP</sub> , Output Off	—	0.1	10	µA
I <sub>DD</sub>	Supply Current	Output Open, T <sub>A</sub> = +25°C	—	3	3.5	mA
		Output Open, T <sub>A</sub> = -40°C to +150°C	—	—	4	mA
I <sub>DD_R</sub>	Reverse Supply Current	V <sub>DD</sub> = -18V, T <sub>A</sub> = +25°C	—	0.6	—	µA
		V <sub>DD</sub> = -18V, T <sub>A</sub> = -40°C to +150°C	—	0.6	1500	µA
		V <sub>DD</sub> = -28V, T <sub>A</sub> = +25°C	—	1.6	—	µA
		V <sub>DD</sub> = -28V, T <sub>A</sub> = -40°C to +150°C	—	1.6	2500	µA
t <sub>P_ON</sub>	Device Power-On Time (Start-up Time)	V <sub>DD</sub> ≥ 3V, B > B <sub>OP</sub> (Note 7)	—	10	—	µs
f <sub>C</sub>	Chopping Frequency	—	—	800	—	kHz
t <sub>D</sub>	Response Time Delay (Time from Magnetic Threshold Reached to the Start of the Output Rise or Fall)	(Note 9)	—	3.75	—	µs
t <sub>R</sub>	Output Rising Time (External Pull-up Resistor R <sub>L</sub> and Load Capacitance Dependent)	R <sub>L</sub> = 1kΩ, C <sub>L</sub> = 20pF	—	0.2	1	µs
t <sub>F</sub>	Output Falling Time (Internal Switch Resistance and Load Capacitance Dependent)	R <sub>L</sub> = 1kΩ, C <sub>L</sub> = 20pF	—	0.1	1	µs
I <sub>OCL</sub>	Output Current Limit	B > B <sub>OP</sub> (Note 10)	30	—	55	mA
V <sub>Z</sub>	Zener Clamp Voltage	I <sub>DD</sub> = 5mA	28	—	—	V

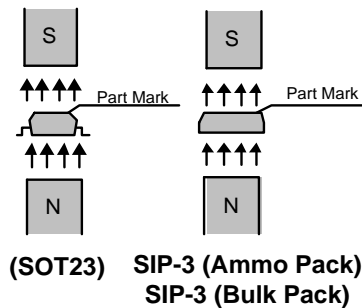
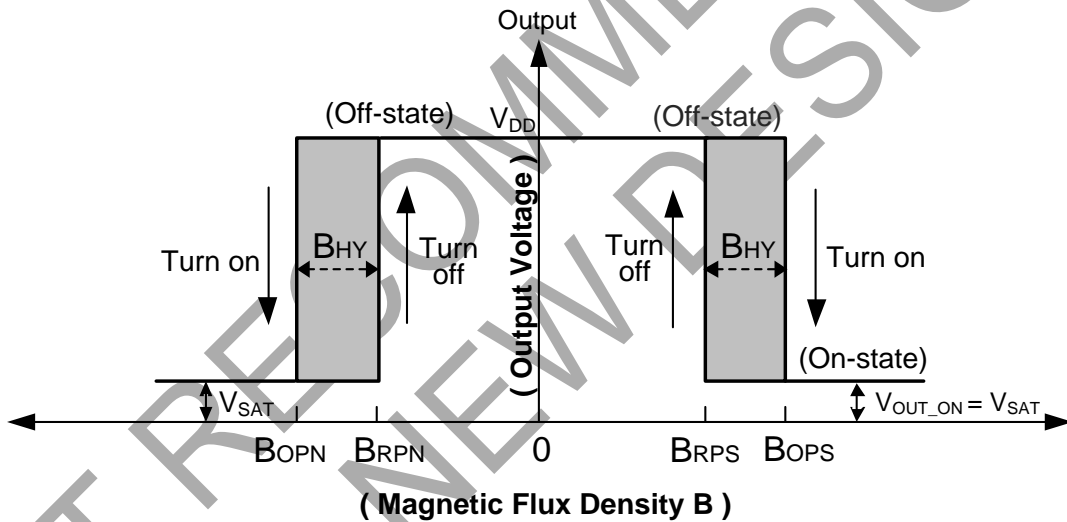
- Notes:
- When power is initially turned on, V<sub>DD</sub> must be within its correct operating range (3.0V to 28V) to guarantee the output sampling. The output state is valid after the start-up time of 10µs typical from the operating voltage reaching 3V.
  - Typical values are defined at T<sub>A</sub> = +25°C, V<sub>DD</sub> = 12V. Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control, and characterization.
  - Guaranteed by design, process control, and characterization. Not tested in production.
  - The device will limit the output current I<sub>OUT</sub> to current limit of I<sub>OCL</sub>.

**Magnetic Characteristics** (Notes 11 and 12) ( $T_A = -40^{\circ}\text{C}$  to  $+150^{\circ}\text{C}$ ,  $V_{DD} = 3.0\text{V}$  to  $28\text{V}$ , unless otherwise specified.)

(1mT = 10 Gauss)

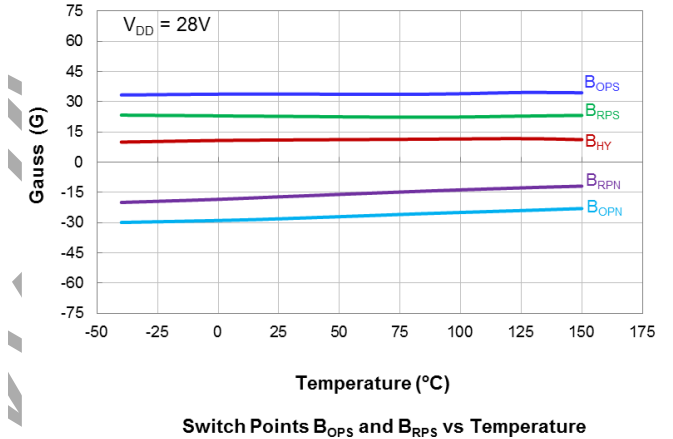
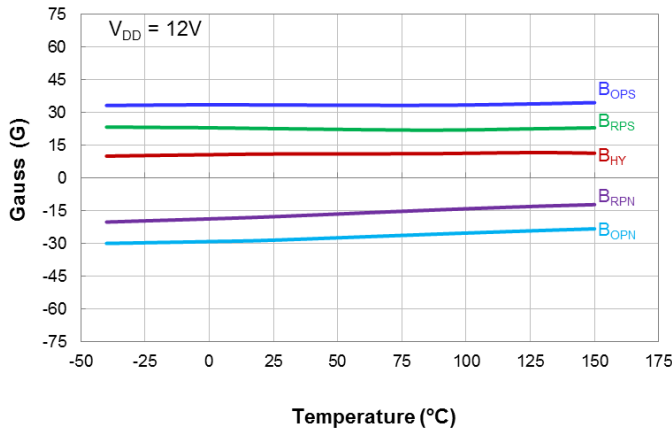
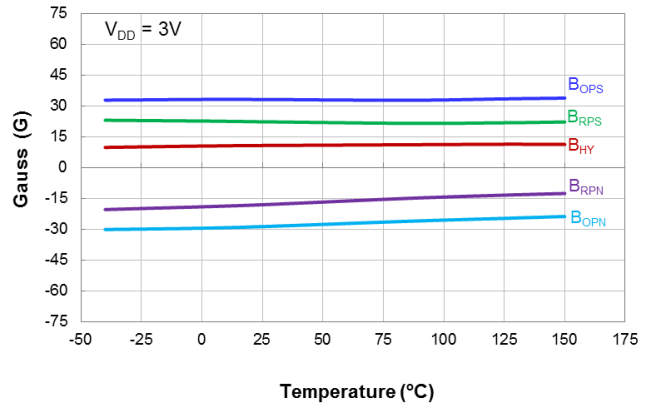
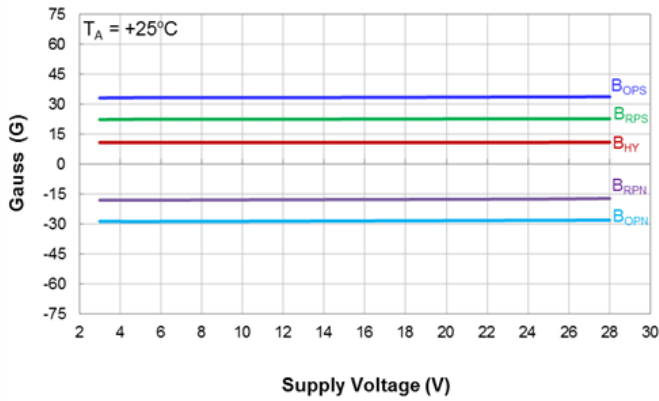
Symbol	Parameter	Condition	Min	Typ	Max	Unit
B <sub>OPS</sub> (South Pole to the Part Marking Side)	Operation Point	$V_{DD} = 12\text{V}$ , $T_A = +25^{\circ}\text{C}$	—	30	—	Gauss
		$T_A = -40^{\circ}\text{C}$ to $+150^{\circ}\text{C}$	15	30	45	
B <sub>OPN</sub> (North Pole to the Part Marking Side)		$V_{DD} = 12\text{V}$ , $T_A = +25^{\circ}\text{C}$	—	-30	—	
		$T_A = -40^{\circ}\text{C}$ to $+150^{\circ}\text{C}$	-45	-30	-15	
B <sub>RPS</sub> (South Pole to the Part Marking Side)	Release Point	$V_{DD} = 12\text{V}$ , $T_A = +25^{\circ}\text{C}$	—	20	—	
		$T_A = -40^{\circ}\text{C}$ to $+150^{\circ}\text{C}$	5	20	35	
B <sub>RPN</sub> (South Pole to the Part Marking Side)		$V_{DD} = 12\text{V}$ , $T_A = +25^{\circ}\text{C}$	—	-20	—	
		$T_A = -40^{\circ}\text{C}$ to $+150^{\circ}\text{C}$	-35	-20	-5	
B <sub>HY</sub> ( $ B_{OPX}  -  B_{RPX} $ )	Hysteresis (Note 13)	$V_{DD} = 12\text{V}$ , $T_A = +25^{\circ}\text{C}$	—	10	—	
		$T_A = -40^{\circ}\text{C}$ to $+150^{\circ}\text{C}$	5	10	18	

- Notes:
- When power is initially turned on,  $V_{DD}$  must be within its correct operating range (3.0V to 28V) to guarantee the output sampling. The output state is valid after the start-up time of 10 $\mu\text{s}$  typical from the operating voltage reaching 3V.
  - Typical values are defined at  $T_A = +25^{\circ}\text{C}$ ,  $V_{DD} = 12\text{V}$ . Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control and characterization.
  - Maximum and minimum hysteresis is guaranteed by design, process control and characterization.

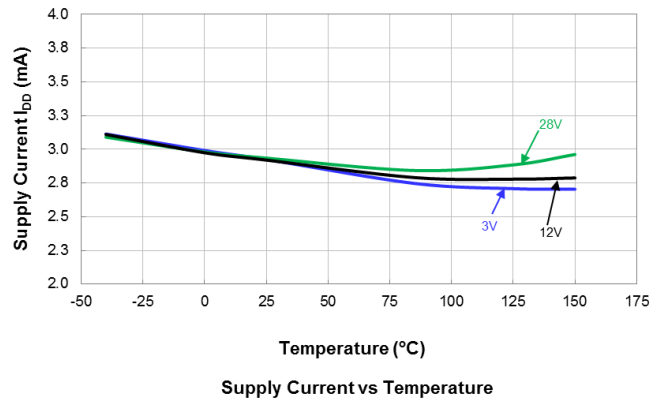
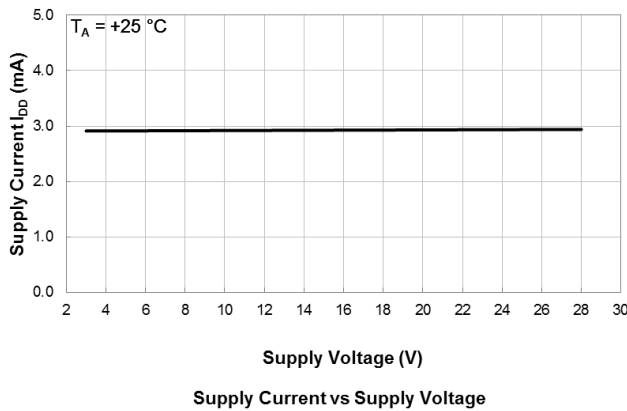


**Typical Operating Characteristics**

**Output Switch Operate and Release Points (Magnetic Thresholds) — B<sub>OPS</sub> and B<sub>RPS</sub>**

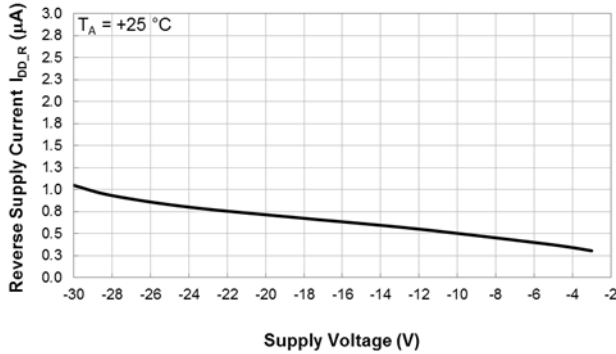


**Supply Current**

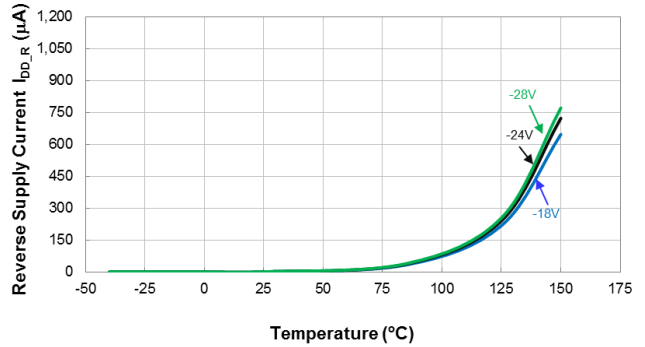


**Typical Operating Characteristics** (Continued)

**Supply Reverse Current**

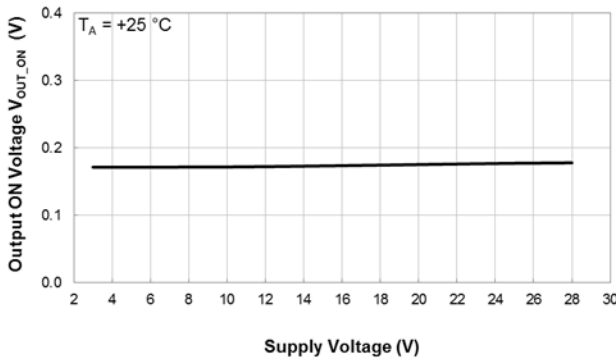


Reverse Supply Current vs Supply Voltage

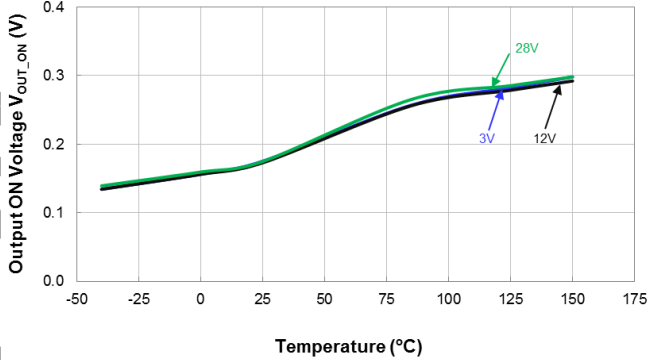


Reverse Supply Current vs Temperature

**Output Switch On Voltage**

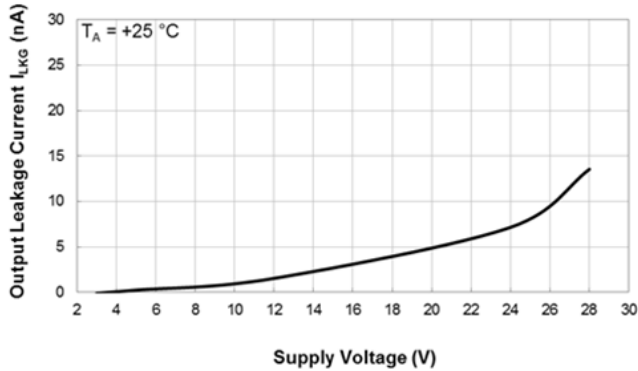


Output ON Voltage vs Supply Voltage

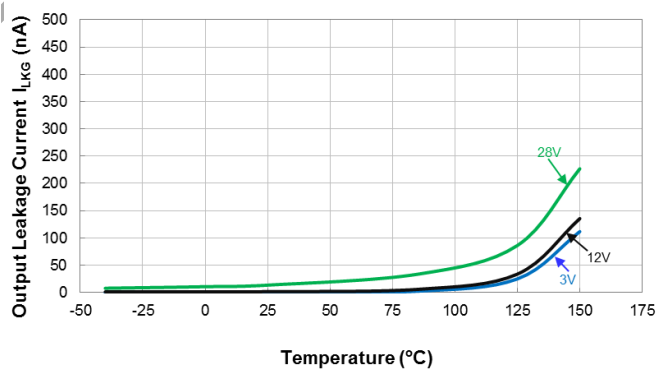


Output ON Voltage vs Temperature

**Output Switch Leakage Current**



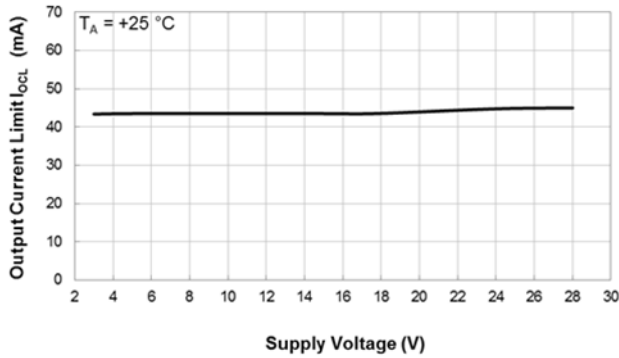
Output Leakage Current vs Supply Voltage



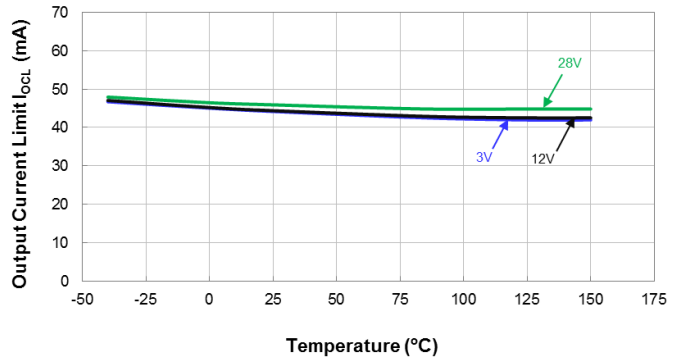
Output Leakage Current vs Temperature

**Typical Operating Characteristics** (Continued)

**Output Current Limit**



Output Current Limit vs Supply Voltage



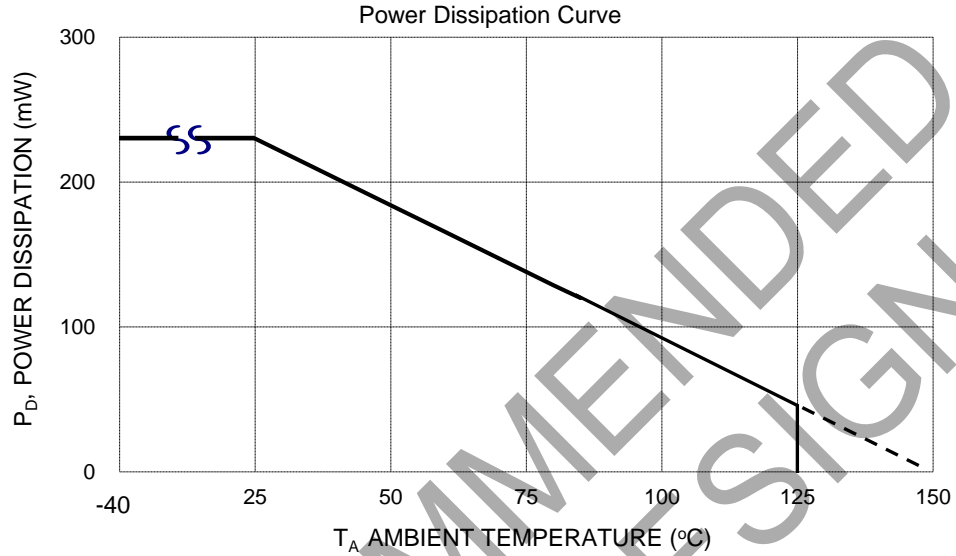
Output Current Limit vs Temperature

NOT RECOMMENDED FOR NEW DESIGN

**Thermal Performance Characteristics**

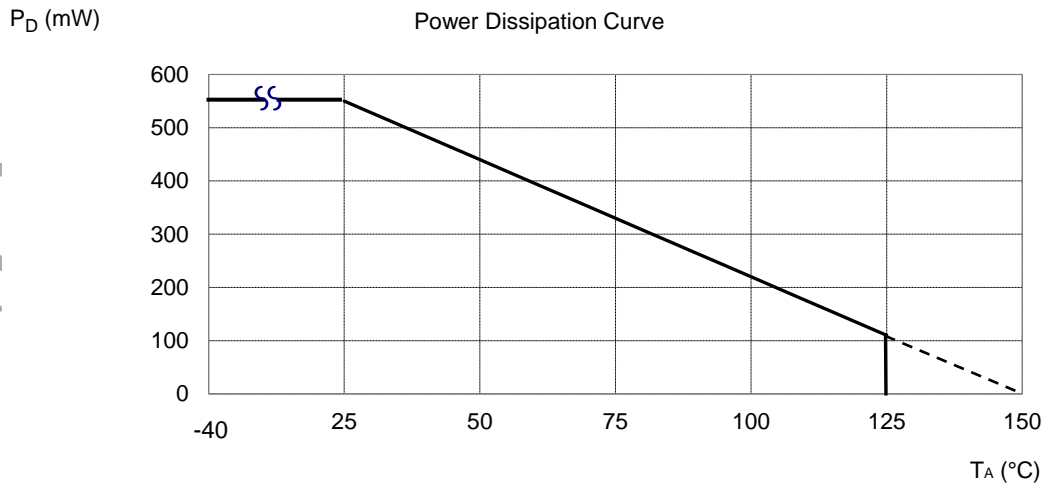
**(1) Package Type: SOT23**

T <sub>A</sub> (°C)	25	50	60	70	80	85	90	100	105	110	120	125	130	140	150
P <sub>D</sub> (mW)	230	184	166	147	129	120	110	92	83	74	55	46	37	18	0



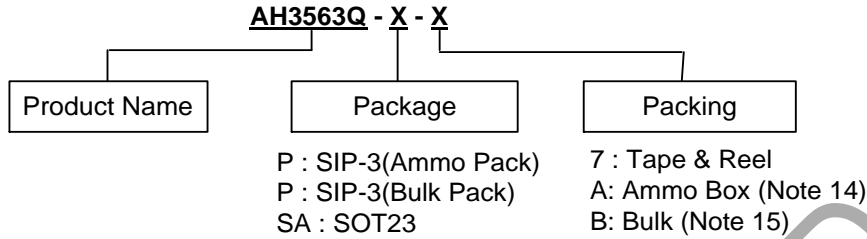
**(2) Package Type: SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)**

T <sub>A</sub> (°C)	25	50	60	70	80	85	90	100	105	110	120	125	130	140	150
P <sub>D</sub> (mW)	550	440	396	362	308	286	264	220	198	176	132	110	88	44	0





**Ordering Information**



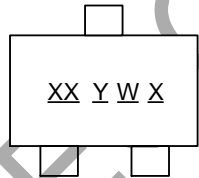
Part Number	Package Code	Packaging	Bulk		Ammo Box		7" Tape and Reel	
			Quantity	Part Number Suffix	Quantity	Part Number Suffix	Quantity	Part Number Suffix
AH3563Q-P-A	P	SIP-3 (Ammo Pack)	NA	NA	4,000/Box	-A	NA	NA
AH3563Q-P-B	P	SIP-3 (Bulk Pack)	1000	-B	NA	NA	NA	NA
AH3563Q-SA-7	SA	SOT23	NA	NA	NA	NA	3,000/Tape & Reel	-7

Notes: 14. Ammo Box is for SIP-3 (Ammo Pack) Spread Lead.  
15. Bulk is for SIP-3 (Bulk Pack) Straight Lead.

**Marking Information**

(1) Package Type: SOT23

( Top View )

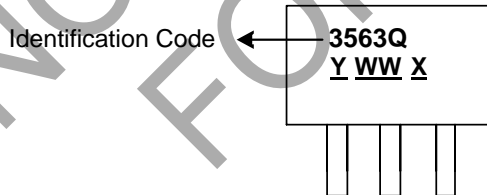


XX : Identification Code  
Y : Year 0 to 9  
W : Week : A to Z : 1 to 26 Week;  
 a to z : 27 to 52 Week; z Represents  
 52 and 53 Week  
X : Internal Code

Part Number	Package	Identification Code
AH3563Q-SA-7	SOT23	Z3

(2) Package Type: SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)

( Top View )



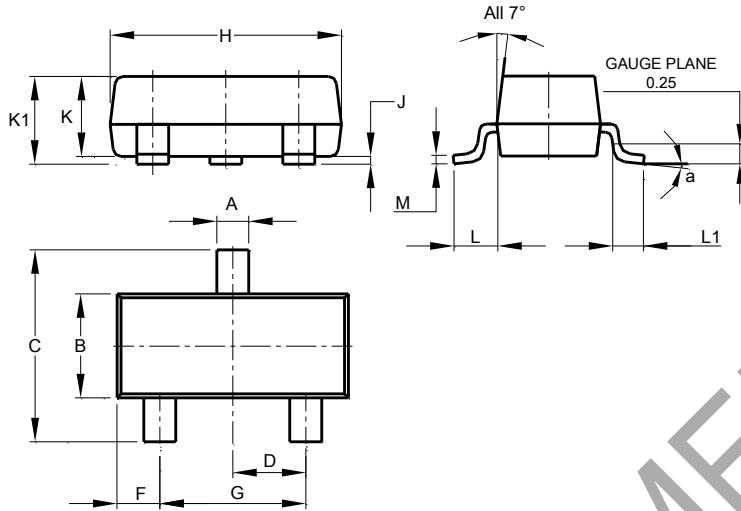
Y : Year : 0 to 9  
WW : Week : 01 to 52, "52" Represents  
 52 and 53 Week  
X : Internal Code

Part Number	Package	Identification Code
AH3563Q-P-A	SIP-3 (Ammo Pack)	3563Q
AH3563Q-P-B	SIP-3 (Bulk Pack)	3563Q

**Package Outline Dimensions** (All dimensions in mm.)

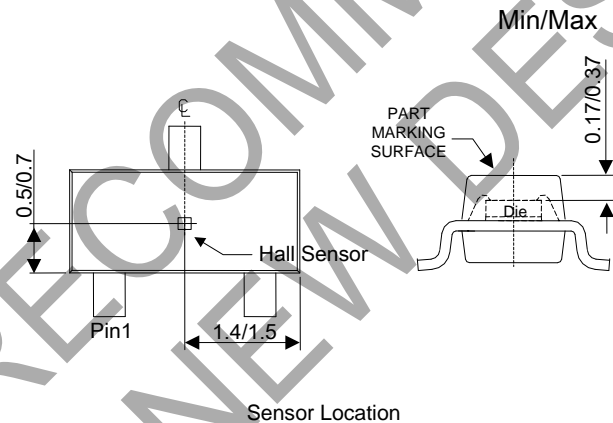
Please see <http://www.diodes.com/package-outlines.html> for the latest version.

(1) Package Type: SOT23



SOT23			
Dim	Min	Max	Typ
A	0.37	0.51	0.40
B	1.20	1.40	1.30
C	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
H	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.890	1.00	0.975
K1	0.903	1.10	1.025
L	0.45	0.61	0.55
L1	0.25	0.55	0.40
M	0.085	0.150	0.110
a	0°	8°	—

All Dimensions in mm

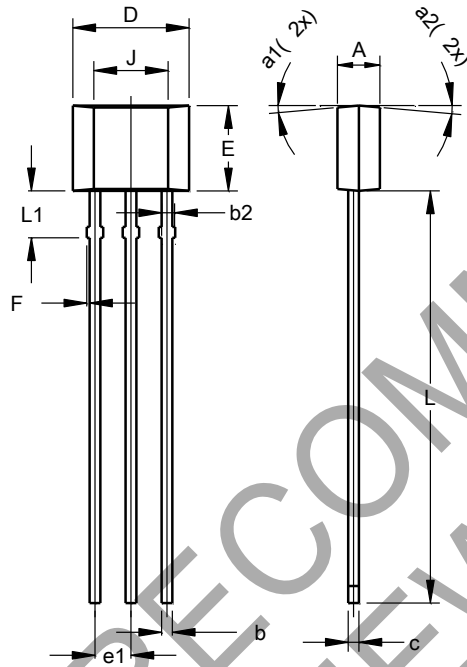
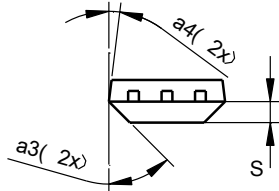


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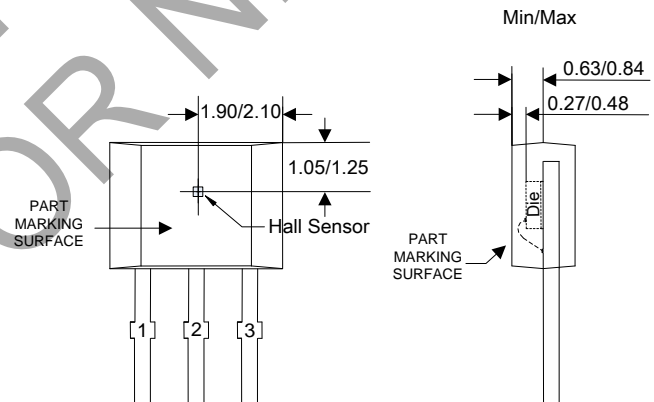
**Package Outline Dimensions** (Continued) (All dimensions in mm.)

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

(2) Package Type: SIP-3 (Bulk Pack)



SIP-3 (Bulk Pack)			
Dim	Min	Max	Typ
A	1.40	1.60	1.50
b	0.33	0.43	0.38
b2	0.40	0.508	0.46
c	0.35	0.41	0.38
D	3.90	4.30	4.10
E	2.80	3.20	3.00
e1	1.24	1.30	1.27
F	0.00	0.20	--
J	2.62 REF		
L	14.00	15.00	14.50
L1	1.55	1.75	1.65
S	0.63	0.84	0.74
a1	--	--	5°
a2	--	--	5°
a3	--	--	45°
a4	--	--	3°
All Dimensions in mm			

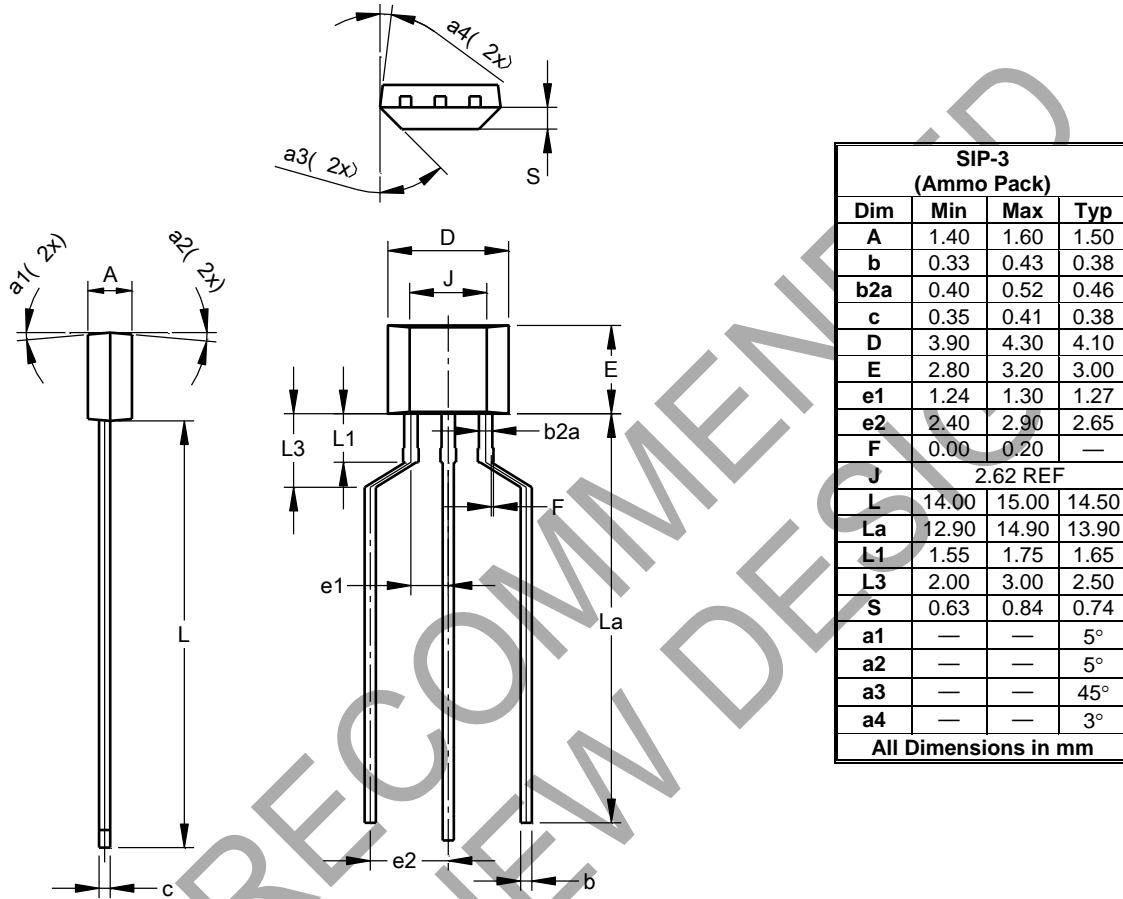


**Sensor Location**

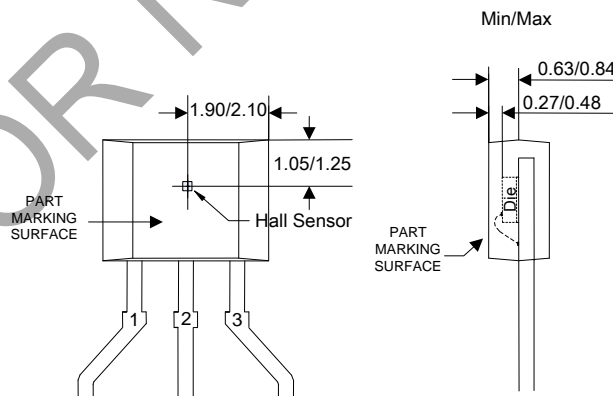
**Package Outline Dimensions** (Continued) (All dimensions in mm.)

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

(3) Package Type: SIP-3 (Ammo Pack)



SIP-3 (Ammo Pack)			
Dim	Min	Max	Typ
A	1.40	1.60	1.50
b	0.33	0.43	0.38
b2a	0.40	0.52	0.46
c	0.35	0.41	0.38
D	3.90	4.30	4.10
E	2.80	3.20	3.00
e1	1.24	1.30	1.27
e2	2.40	2.90	2.65
F	0.00	0.20	—
J	2.62 REF		
L	14.00	15.00	14.50
La	12.90	14.90	13.90
L1	1.55	1.75	1.65
L3	2.00	3.00	2.50
S	0.63	0.84	0.74
a1	—	—	5°
a2	—	—	5°
a3	—	—	45°
a4	—	—	3°
All Dimensions in mm			

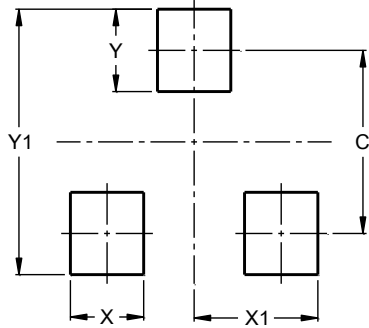


Sensor Location

## Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

(1) Package Type: SOT23



Dimensions	Value (in mm)
C	2.0
X	0.8
X1	1.35
Y	0.9
Y1	2.9

## Mechanical Data

### SOT23 Package

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.009 grams (Approximate)

### SIP-3 (Bulk Pack), SIP-3 (Ammo Pack) Packages

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.12 grams (Approximate)

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